NSN 5961-01-085-3418

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Inclosure Material:

Metal

Overall Length:

0.375 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Internal Junction Configuration:

Pn

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

90.0 drain supply voltage and 90.0 drain to gate voltage and 15.0 forward gate to source voltage

Current Rating Per Characteristic:

2.00 amperes source cutoff current of standard range and 2.00 milliamperes zero-gate-voltage source current horsepower metric

Power Rating Per Characteristic:

25.0 watts small-signal input power, common-collector

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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